

Faculty of Engineering School of Photovoltaic and Renewable Energy Engineering

### Solcore Workshop – Silicon Tandem Cell Computer Modelling

Sungkyunkwan University, 1 – 3 August 2023

N.J. Ekins-Daukes & Phoebe Pearce

✓ nekins@unsw.edu.au



EkinsNed





Faculty of Engineering School of Photovoltaic and Renewable Energy Engineering



## **Session 1: Introduction**

1 August 2023

Ned Ekins-Daukes, Phoebe Pearce



A Role for Computer Simulation in the Modern Technological Innovation Process



"Think Play Do: technology, innovation and organisation", Mark Dodgson, David Gann and Ammon Salter, 2005, Oxford University Press, ISBN 9780199268092



## The Present Value of Computer Modelling in Research & Development





## The Future Value of Computer Modelling in Research & Development



Rachel Kurchin, Giuseppe Romano, & Tonio Buonassisi, 'Bayesim: A tool for adaptive grid model fitting with Bayesian inference'. Computer Physics Communications, (2019)



**Development Process for our Computer Code:** 





## **Solcore capabilities**





## **RayFlare capabilities**



https://rayflare.readthedocs.io



## **Course instructions**

**GitHub repository** where the tutorials for this workshop are hosted:



To run Solcore & RayFlare on your own computer, you will need to install Python (version 3.7 to 3.11), and then:

#### pip install solcore rayflare seaborn

Recommendations for installing Python:

- On Windows, use miniconda (https://conda.io/miniconda.html)
- On MacOS, use Homebrew + venv (see RayFlare's installation instructions for more detail)
- On **Ubuntu/Linux**, use **system Python + venv** (see RayFlare's installation instructions for more detail)



## Binder

0

 $\equiv$ 

\*

• Binder may take a long time (~ 10 minutes) to load, so please click the link to 'Launch Binder' now







## **Example: Si cell emissivity**



Simulations & measurement of cell absorptivity (emissivity) between 300 nm and 20  $\mu$ m. This is relevant for the operating temperature of the cell. Due to free-carrier absorption in doped layers and very good light-trapping, the cell absorbs well even at wavelengths far beyond the bandgap.



D. Alonso-Álvarez et al., 'Thermal emissivity of silicon heterojunction solar cells', Solar Energy Materials and Solar Cells, vol. 201, no. May, p. 110051, 2019, doi: <u>10.1016/j.solmat.2019.110051</u>.



## Example: ultra-thin GaAs cell







[1] L. Sayre *et al.*, 'Ultra-thin GaAs solar cells with nanophotonic metal-dielectric diffraction gratings fabricated with displacement Talbot lithography', *Progress in Photovoltaics*, vol. 30, no. 1, pp. 96–108, Jan. 2022, doi: <u>10.1002/pip.3463</u>.



## Example: ultra-thin GaAs cell (cont.)





## Example: Perovskite/Si tandem cell



[1] Sahli, F., Werner, J., et al. (2018) 'Fully textured monolithic perovskite/silicon tandem solar cells with 25.2% power conversion efficiency', *Nature Materials*. Springer US, 17(9), pp. 820–826.



## Example: Perovskite/Si tandem cell (cont.)



From [1]

As a result of the front surface texture:

- Peak in R around 830 nm is reduced (lower front-surface reflectivity)
- Perovskite absorption slightly enhanced
- Boosts long-wavelength absorption (better light-trapping inside Si)



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## Session 2: Hands-on exercise Using SolCore to calculate the Shockley-Queisser Efficiency limit

1 August 2023

Ned Ekins-Daukes, Phoebe Pearce



## What is the Maximum Efficiency of a Solar Cell?

**Trivich-Flynn Limit (1955)** 



#### Warning : Limit is invalid for T > 0K !

Trivich D, Flinn PA. Maximum efficiency of solar energy conversion by quantum processes. In Solar Energy Research, Daniels F, Duffie J (eds). Thames and Hudson: London, 1955.

Green, Martin A. 'Analytical treatment of Trivich-Flinn and Shockley-Queisser photovoltaic efficiency limits using polylogarithms'. Progress in Photovoltaics: Research and Applications, 20(2) (2012) 127



## **Limit to the Short-Circuit Current**





p87

18

## What is the Maximum Efficiency of a Solar Cell?

**Shockley Queisser limit (1961)** 



Shockley, William, & Queisser, Hans J. 'Detailed Balance Limit of Efficiency of p-n Junction Solar Cells'. Journal of Applied Physics, 32(3) (1961) 510 https://doi.org/10.1063/1.1736034

19 UNSV

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## Session 3: Shockley-Queisser efficiency limit & detailed balance junction model

1st August 2023

Ned Ekins-Daukes, Phoebe Pearce



## **Optical Models for PV Devices**

**Fundamental** 

#### Shockley-Queisser (Detail Balance)

Complete absorption to band-gap energy Eg

Eg



**Beer Lambert Law** 

 $I = I_0 e^{-\alpha d}$ 

Intensity of light is attenuated exponentially with increasing thickness of absorber d [m] . Absorption defined by a wavelength dependent absorption coefficient  $\alpha(\lambda)[m^{-1}]$ 



#### **Ray Optics**

Non-uniform surfaces or PV structures  $\gg \lambda$ 

Surface texture of a silicon solar cell

#### Wave Optics

#### Sub-wavelength structures $\ll \lambda$

Anti-reflection coating 90nm p-doped layer

800nm n-doped layer



Diffractive grating on rear side.



















## **Electrical Models for PV Devices**

#### **Fundamental**

#### Shockley-Queisser (Detail Balance)

Band-gap : Eg Temperature : T



#### **Depletion approximation**

Analytical solutions to the driftdiffusion equations for homogeneous layers. Shockley Diode Eqn

Band-gap : EgMobility  $\mu$ Temperature : TSurfaceDiode dimensions: xrecombination Sn,SpDoping level: Na, NdDiffusion length L,AbsorptionMinority carriercoefficient  $\alpha$ lifetime  $\tau$ 



# Numerical solution to the semiconductor drift-diffusion equations: 1D, 2D, 3D

Spatial variation of all parameters previously used in the depletion approximation.

- Variable doping profile within a region (silicon PV)
- Variable band-gap within a region (CIGS PV)

Eg

• Mobile ions under dark and illuminated conditions (Perovskite PV)





## **General Form of the Planck Equation**



900K

Tungsten-Halogen light bulb



2800K



5800K





Generalised Planck Equation: P.Würfel, J.Phys C, Vol 15, 18(1982) p.3967



# Semiconductors are "Grey" bodies



## Electroluminescence



## Verification of the Generalised Planck Expression



J.Phys: Condens.Matter 2 (1990) p.3803

# Radiative limit to Jo

Emissivity

Eg

λ

$$\dot{N} = \int_{Eg}^{E_{top}} \epsilon(E) \frac{2\pi}{c^2 h^3} \frac{E^2}{e^{\frac{E-\mu}{kT}} - 1} dE$$

•Assume F(E) Boltzmann approximation •Bands are infinite ( $E_g \rightarrow \infty$ )

$$\dot{N} = \int_{Eg}^{\infty} \epsilon(E) \frac{2\pi}{c^2 h^3} \frac{E^2}{e^{\frac{E-\mu}{kT}}} dE$$

$$= \underbrace{\left(\epsilon kT (Eg^2 + 2EgkT + 2k^2T^2) e^{\frac{-Eg}{kT}}\right)}_{I} e^{\frac{\mu}{kT}} \quad \mu = qV$$

$$J = J_0 e^{\frac{qV}{kT}}$$

## **Unpacking the Shockley Queisser Efficiency limit:**



L. Hirst & N.J.Ekins-Daukes, Progress in Photovoltaics, (2011) 19: p286, M.A. Green, & A.W.Y. Ho-Baillie, ACS Energy Letters, 4(7) (2019) 1639



-0

GaAs

GaInP

00

0

Si

0.







## Understanding the effect of solar concentration



$$qV_{max} = E_g - E_g \frac{T_A}{T_s} - kT_A \ln\left(\frac{\Omega_{emit}}{\Omega_{abs}}\right)$$
  
Boltzmann loss  
Conventional solar cell Maximum concentration  
$$\mathcal{N}$$

L. Hirst & N.J.Ekins-Daukes, Progress in Photovoltaics, (2011) 19: p286

#### $\Omega_{\text{emit}} = \Omega_{\text{abs}}$ M. Maximum concentration or restricted emission $\Omega_{emit}$ $E_g \frac{T_A}{T_S}$ $kT_A \ln$ $\Omega_{abs}$ 1000 particle number (multiplied by electronic charge) 900 800 ANY A emission 700 Boltzmann Concentrator System Carnot 600 below Eg 500 Carnot Vopt Eg 400 Boltzmann - Market 300 Conventional solar cell $\Omega_{emit} >> \Omega_{abs}$ power out 200••••• current-voltage characteristic 100thermalisation 0 0.5 3.5 0 1.5 4.5 5

## Understanding the effect of solar concentration :

L. Hirst & N.J.Ekins-Daukes, Progress in Photovoltaics, (2011) 19: p286

4

2.5

particle energy (eV)

3

36


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#### Day 2 Solcore Workshop – Silicon Tandem Cell Computer Modelling

Sungkyunkwan University, 1 – 3 August 2023

International Energy Joint R&D Project : Silicon / III-V Tandem solar cell to achieve over 40% efficiency. Supported financially by KETEP (Korean Energy Technology Evaluation and Planning)

Ned Ekins-Daukes & Phoebe Pearce



# Summary of Day 1:





# **Importing the Solar Spectrum and Plotting**

```
import numpy as np
 1
     import matplotlib.pyplot as plt
 2
     from solcore.light_source import LightSource
 3
     import seaborn as sns
 4
 5
 6
     # Setup the AM1.5G solar spectrum
     wl = np.linspace(300, 4000, 4000) * 1e-9 #wl contains the x-ordinate in wavelength
 7
     am15g = LightSource(source_type='standard', x=wl*1e9, version='AM1.5g')
 8
 9
                                                                                                           Spectral Irradiance
     plt.figure(1)
10

    AM1.5G

                                                                                              1.6
                                                                                              1.4
     plt.title('Spectral Irradiance')
11
                                                                                            1.2 (Wm<sup>-2</sup> nm<sup>-1</sup>)
0.8 (Wm<sup>-2</sup> nm<sup>-1</sup>)
     plt.plot(*am15g.spectrum(wl*1e9), label='AM1.5G')
12
     plt.xlim(300, 3000)
13
                                                                                             del
                                                                                              0.6
                                                                                            Dower
0.4
     plt.xlabel('Wavelength (nm)')
14
     plt.ylabel('Power density (Wm$^{-2}$nm$^{-1}$)')
15
                                                                                              0.2
                                                                                              0.0
16
     plt.legend()
                                                                                                 500
                                                                                                       1000
                                                                                                             1500
                                                                                                                  2000
                                                                                                                        2500
                                                                                                            Wavelength (nm)
```



3000

### Calculating a Detailed-Balance IV curve in SolCore (Shockley-Queisser limit)

```
eq=1.42
12
     V = np.linspace(0, 1.3, 500)
13
14
     db_junction = Junction(kind='DB', T=300, Eg=eg, A=1, R_shunt=np.inf, n=1)
    my_solar_cell = SolarCell([db_junction], T=300, R_series=0)
15
16
     solar_cell_solver(my_solar_cell, 'iv',
17
18
                              user_options={'T_ambient': 300, 'db_mode': 'top_hat', 'voltages': V,
                               'light_iv': True,
                                              'internal_voltages': np.linspace(0, 1.3, 400),
19
                                               'wavelength': wl,
                                               'mpp': True, 'light_source': am15g})
20
        my_solar_cell
                                                                                                        Limiting Efficiency IV curve for Eg=1.42e
                                                             my_solar_cell
                                                                                                      Jsc 320 25
                                                                                                      Pmax 326.50
         db_junction
                                                                  db_junction
                                    Solar_cell_solver
                                                                                                  °⊑ 200
                                                                                                  IIII 150
         Eg=1.42, T=300
                                                                  Eg=1.42, T=300
                                                             Isc=320.25 Pmax=326.5 Voc=1.14
                                                                                                             0.6 0.8
                                                                                                          0.4
                                                                                         FF=89.3%
                                                             print (my solar cell.iv.Isc)
```



### **Detail Balance Double Junction Tandem Solar Cell**





# Summary of Day 1:





### **Spectral Irradiance changes throughout the day:**







### **Spectral Irradiance Models**

SPCTRL2	SMARTS2	SBDart	MODTRAN	FASCO	DE
Clear Sky	AM1.5G standard	Clear Sł	xy + Cloudy Co	onditions	
Complexity / computational time					

Empirical closed	Parameterisation	band-model of
form	based on MODTRAN	HITRAN
transmission.	output.	Database

Domain of solar system engineering

Implemented in SolCore

Domain of atmospheric physics



**HITRAN** 

Database

# **Spectral Irradiance changes throughout the day:**



$$AOD = \beta \lambda^{-\alpha}$$

SPCTRL2	SMARTS2
Clear Sky	AM1.5G standard
Air Mass	

- Latitude, Longitude, Time of day
- Aerosol type :
  - Shettle & Fenn models:
    - Rural, Urban, Maritime, Tropospheric
- Aerosol concentration
  - Aerosol optical depth (AOD)
  - Atmospheric turbidity ( $\beta$ )
  - Ångström coefficient (α)
- Precipitable Water column thickness
- Meteorological conditions:
  - Pressure
  - Humidity
  - Ozone



### **Effect of Aerosol Optical Density on Solar Spectral Irradiance**





# **Complex atmospheres in India**





http://www.nrel.gov/international/ra\_india.html



N. L. A. Chan, et al., IEEE JPV 4 (5), pp. 1306–1313, 2014.



# **Atmospheric variation worldwide**





Chan, N.L.A., et al., Progress in Photovoltaics, 22(10), p.1080 (2014).



# **Semiconductor Drift-Diffusion Equations**

For electrons:

Numerical solution to D-D eqns for QE: Xiaofeng Li, *Prog. Photovolt: Res. Appl.*, vol. 21, no. 1, pp. 109–120, 2013. Analytical solution to D-D eqns for QE: Jenny Nelson, The Physics of Solar Cells, Imperial College Press, 2003



**Carrier collection probability at short-circuit (V=0)** 







#### **Recombination terms:**





#### Silicon n/p solar cell : 0V Dark





#### 2.5 10<sup>19</sup> Generation and Recombination / $s^{-1}$ 2 10<sup>19</sup> Cumulative generation & n recombination 1.5 10<sup>19</sup> Generation p Recombination 1 10<sup>19</sup> 5 10<sup>18</sup> 1 0 0 50 100 150 200 250 300 Electron quasi-Fermi Level 0.5 Distance from front surface / µm 10<sup>20</sup> Carrier density Hole quasi-Fermi Level 10<sup>18</sup> Energy / eV 0 . . . . 10<sup>16</sup> L Carrier Concentration / cm<sup>-3</sup> 10<sup>14</sup> -0.5 10<sup>12</sup> 10<sup>10</sup> 10<sup>8</sup> -1 10<sup>6</sup> 10<sup>4</sup> Band diagram 100 -1.5 2 3 0 5 4 1 2 5 0 3 1 4 Distance from front surface / µm Distance from front surface / µm

#### Silicon n/p solar cell : 0V Illuminated - AM1.5G



Silicon n/p solar cell : Maximum power point Vmax Illuminated AM1.5G







# p/n Junction : Depletion approximation





# p/n Junction : Depletion approximation





#### **Depletion approximation model for QE**

Jn / Jp	Minority electron/hole current density	
R	Surface reflection	
α	Absorption coefficient	
Ln / Lp	Minority electron, hole diffusion length	
xp / xn	width of p / n regions	
Dn / Dp	Carrier diffusivity for electrons and holes	
wn / wp	Depletion widths on n/p side of the junction	
n0/p0	Equilibrium electron/hole carrier density	
Sn/Sp	Front / Rear surface recombination velocity	
τη/τρ	Electron / hole minority carrier lifetime	
ni	Intrinsic carrier concentration	
Т	Junction temperature	
V	External junction bias	



$$J_{n}(E, w_{p}) = J_{scr}(E, w_{n}, w_{p}) = qb_{s}(1-R)e^{-\alpha(x_{p}-w_{p})}(1-e^{-\alpha(w_{p}+w_{n})})$$

$$\left(\frac{qb_{s}(1-R)\alpha L_{n}}{\alpha^{2}L_{n}^{2}-1}\right) - \left(\frac{(\frac{S_{n}L_{n}}{D_{n}} + \alpha L_{n}) - e^{-\alpha(x_{p}-w_{p})}(\frac{S_{n}L_{n}}{D_{n}} \cosh \frac{x_{p}-w_{p}}{L_{n}} + \sinh \frac{x_{p}-w_{p}}{L_{n}})}{\frac{S_{n}L_{n}}{D_{n}} \sinh \frac{x_{p}-w_{p}}{L_{n}} + \cosh \frac{x_{p}-w_{p}}{L_{n}}} - \alpha L_{n}e^{-\alpha(x_{p}-w_{p})}\right)$$

$$J_p(E, w_n) = \left(\frac{qb_s(1-R)\alpha L_p}{\alpha^2 L_p^2 - 1}\right)e^{-\alpha(x_p + w_n)}$$
$$\left(\alpha L_p - \frac{\frac{S_p L_p}{D_p}\cosh\frac{x_n - w_n}{L_p} - e^{-\alpha(x_n - w_n)} + \sinh\frac{x_n - w_n}{L_p}) + \alpha L_p e^{-\alpha(x_n - w_n)}}{\frac{S_p L_p}{D_p}\sinh\frac{x_n - w_n}{L_p} + \cosh\frac{x_n - w_n}{L_p}}\right)$$

J.Nelson, Physics of Solar Cells, Imperial College Press 2003

#### p/n Junction Diode : Dark-IV





#### Shockley Read Hall Recombination

$$\begin{array}{rcl} J(V) &\approx & J_0(e^{\frac{qV}{kT}}-1) & \leftarrow \text{Diffusion} \\ &+ & J_1(e^{\frac{qV}{2kT}}-1) & \leftarrow \text{Impurity} \end{array}$$

# Shockley Read Hall (SRH) recombination



- Non-radiative process
- Releases phonons

# Deep & shallow levels



•Shallow levels are ionized at room temperature and can donate or accept electrons •Deep levels trap carriers





C.-T. Sah, R. Noyce, and W. Shockley, Proceedings of the IRE 45, 1228–1243 (1957).

# Shockley diode models for $J_0$



Shockley diffusion current (Radiative & non-radiative):

$$J_{01} = \left(\frac{qD_n n_i^2}{L_n N_A} \cdot \frac{\cosh\left(\frac{W_p}{L_n}\right) + \frac{D_n}{S_n L_n} \sinh\left(\frac{W_p}{L_n}\right)}{\frac{D_n}{S_n L_n} \cosh\left(\frac{W_p}{L_n}\right) + \sinh\left(\frac{W_p}{L_n}\right)} + \frac{qD_p n_i^2}{L_p N_D} \frac{\cosh\left(\frac{W_n}{L_p}\right) + \frac{D_p}{S_p L_p} \sinh\left(\frac{W_n}{L_p}\right)}{\frac{D_p}{S_p L_p} \cosh\left(\frac{W_n}{L_p}\right) + \sinh\left(\frac{W_n}{L_p}\right)} \cdot \right)$$

Shockley-Read-Hall current: (non-radiative)

$$J_{02} = \frac{qn_i(W_n + W_p)}{\sqrt{\tau_n \tau_p}}$$







# **Auger Recombination**

$$\begin{array}{lll} J(V) &\approx & J_0(e^{\frac{qV}{kT}}-1) \ \leftarrow \mbox{Diffusion} \\ &+ & J_1(e^{\frac{qV}{2kT}}-1) \ \leftarrow \mbox{Impurity} \\ &+ & J_2(e^{\frac{3qV}{2kT}}-1) \ \leftarrow \mbox{Auger} \end{array}$$





- Three particle process
  - e.g. two electrons one hole shown
- Momentum must be conserved
- Favoured at high carrier density
- Somewhat material dependent (m\*)



# **Fill Factor**





J.Nelson, The Physics of Solar Cells, Imperial College Press 2003



# Silicon solar cells are approaching the Auger limit



Lin, Hao, et al., *Nature Energy*, (2023) doi:10.1038/s41560-023-01255-2 Green, M.A. *Nature Energy*, (2023) doi:10.1038/s41560-023-01296-7 64



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# Session 5: Simple Si and GaAs cells using the depletion approximation

2nd August 2023

Ned Ekins-Daukes, Phoebe Pearce



### **Example 5a: Simple Si cell**

Si is considered infinitely thick, with 200 µm of absorbing thickness (ignore back-surface reflection)



Beer-Lambert absorption: Fresnel eqn + Beer- $I(z) = I_0 e^{-a(\lambda) z}$ Lambert absorption:  $I_0 = 1$ 

 $I(z) = I_0(\lambda) e^{-\alpha(\lambda) z}$  $I_0(\lambda) = 1 - R(\lambda)$ 

Transfer matrix method (Si treated *incoherently*)

Add ARC, Transfer-matrix method

66



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#### Sessions 6 & 7: Transfer-matrix method

2nd August 2023

Ned Ekins-Daukes, Phoebe Pearce



# **Transfer-matrix method (TMM) in Solcore**

### **Defining structures**



#### **Modelling optics**

Transfer-matrix method (TMM)



TMM: S. J. Byrnes, "Multilayer optical calculations." arXiv, Dec. 30, 2020



### **Example 6a: More exploration of TMM**

No longer ignore back-surface reflection. Explore effect of different assumptions about coherency, the incidence angle, and the polarization of the incident light





## **Example 6b: Simple ARC optimization**

Find ARC layer thicknesses which minimize reflectance



Vary d

Vary  $d_1$  and  $d_2$ 



### Example 7: Planar GalnP/Si cell (2-terminal vs. 4-terminal)

Material	Thickness (nm)	Contrib. to jsc
air	0	0
MgF <sub>2</sub>	97	0
ZnS	41	0
n-Al <sub>0.52</sub> In <sub>0.48</sub> P	17 (20)	0
n-Ga <sub>0.5</sub> In <sub>0.5</sub> P	950 (1000)	0.91
p-Al <sub>0.27</sub> Ga <sub>0.26</sub> In <sub>0.47</sub> P	200	0
p-Al <sub>0.5</sub> Ga <sub>0.5</sub> As	500	0
ZnS	82	0
epoxy	10,000	0
glass, n=1.56	1,000,000	0
epoxy	10,000	0
PECVD SiO <sub>x</sub>	100	0
SiN <sub>x</sub> , n=1.91	70	0
SiN <sub>x</sub> , n=2.4	15	0
	357,000	
n,p-Si	(150,000)	1
Al <sub>2</sub> O <sub>3</sub>	15	0
SiN <sub>x</sub> , n=1.91	120	0
Al	10,000	0



Note: the paper uses a textured Si bottom cell, while we assume all interfaces are planar. We will discuss the use of textures in III-V/Si and perovskite/Si tandem cells tomorrow.

#### https://doi.org/10.1109/PVSC40753.2019.9198960





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#### Sessions 8 - 10: Advanced optical modelling

3rd August 2023

Phoebe Pearce, Ned Ekins-Daukes


## **RayFlare installation**

- Previously, we have used **Solcore** for all the examples.
  - Solcore has quite a lot of optics capabilities, but it cannot do ray-tracing
  - **RayFlare** is our dedicated optics package; it can reproduce what Solcore does, but also adds new functionality:
    - Ray-tracing
    - Angular redistribution matrix method (ARMM)
- Please go to **rayflare.readthedocs.io** and read the installation instructions
  - Basic installation: pip install rayflare
  - This will install everything except RCWA functionality (for diffraction gratings/2D periodic structures)
  - Installation instructions for RCWA functionality can be found in the documentation. Unfortunately, it does not work on Windows (but all other RayFlare functionality does work!)
- More instructions for running Linux inside Windows: <u>http://docs.solcore.solar/en/latest/Installation/Solcore\_on\_Windows.html</u>



## **RayFlare capabilities**



#### Documentation: <u>https://rayflare.readthedocs.io</u>

P. Pearce, 'RayFlare: flexible optical modelling of solar cells', *Journal of Open Source Software*, vol. 6, 74 no. 65, p. 3460, 2021, doi: 10.21105/joss.03460.



## **Transfer-matrix method (TMM)**

#### **Defining structures**



#### **Modelling optics**

Transfer-matrix method (TMM)





TMM: S. J. Byrnes, "Multilayer optical calculations." *arXiv*, Dec. 30, 2020

#### **Ray-tracing**



Reflection and transmission probabilities can be calculated using the Fresnel equations (for simple interfaces) or TMM (for interface with thin layers). If using TMM, can also calculate absorption per layer (and absorption profiles)

Further reading: https://doi.org/10.25560/88448 (P. Pearce PhD thesis)



#### **Rigorous coupled-wave analysis (RCWA)**

(Also called the "Fourier Modal Method")

A method for solving Maxwell's equations, which transforms the problem to the frequency domain (for structures which are periodic in two dimensions).

Keeping more "Fourier orders" should make the solution more accurate, but increases the computation time



Kinc

Layer 0





[1] H.-L. Chen *et al.*, *Nature Energy*, vol. 4, no. September, 2019, doi: <u>10.1038/s41560-019-0434-y</u>.
 [2] https://web.stanford.edu/group/fan/S4



#### **Angular Redistribution Matrix Method**







[1] N. Tucher *et al.*, *Optics Express*, vol. 23, no. 24, p. A1720, 2015, doi: <u>10.1364/OE.23.0A1720</u>.

# 

#### Further reading: https://rayflare.readthedocs.io/en/latest/Theory/theory.html

## Using a single method: what does it look like in the code?



RCWA

RCWA\_stack = rcwa\_structure(

structure=[Layer(width\_1, material\_1), Layer(width\_2, material\_2)],
size=((100, 0), (0, 100)), # in nm
options=user\_options,
incidence=Air,transmission=Air)



#### Some more detail about ray-tracing structures: rt\_structure



In rt\_structure, It is assumed that the **bulk layers** (material\_1, material\_2 in the diagram) are thick enough (or absorbing enough) that we can **ignore thin-film interference**.

However, the **interface textures themselves can be modified with additional thin-film layers**! If there are interface layers, RayFlare will first calculate reflection/absorption/reflection probabilities using TMM, and then use these probabilities during the ray-tracing calculation:

```
\rightarrow Fully integrated ray-tracing + TMM, inside <code>rt_structure!</code>
```



## But what if we want to combine other methods?

- Previous slide: integrated ray-tracing + TMM
- But what if we want to integrate e.g.:
  - TMM and RCWA
  - Ray-tracing and RCWA
  - Other methods we define ourselves (or maybe real measured data!)

#### $\rightarrow$ Use the <u>angular redistribution matrix method</u> (ARMM), also called the "OPTOS method"

• Calculate angular redistribution matrices for each surface: how light incident from any angle is scattered by the surface (or absorbed). Use an appropriate method for each surface.

$$\mathbf{R}, \mathbf{T} = \begin{pmatrix} p(\{\theta_1, \phi_1\} \to \{\theta_1, \phi_1\}) & p(\{\theta_1, \phi_2\} \to \{\theta_1, \phi_1\}) & \dots & p(\{\theta_n, \phi_m\} \to \{\theta_1, \phi_1\}) \\ p(\{\theta_1, \phi_1\} \to \{\theta_1, \phi_2\}) & p(\{\theta_1, \phi_2\} \to \{\theta_1, \phi_2\}) & \dots & p(\{\theta_n, \phi_m\} \to \{\theta_1, \phi_2\}) \\ \vdots & \ddots & \vdots \\ p(\{\theta_1, \phi_1\} \to \{\theta_n, \phi_m\}) & p(\{\theta_1, \phi_2\} \to \{\theta_n, \phi_m\}) & \dots & p(\{\theta_n, \phi_m\} \to \{\theta_n, \phi_m\}) \end{pmatrix}$$



#### Figure from: https://doi.org/10.1364/OE.23.0A1720

## **ARMM (continued)**

• Assume Beer-Lambert-like absorption in bulk medium which connects the two surfaces:

$$D = \begin{bmatrix} e^{-\alpha d/|\cos \theta_1|} & 0 & \dots & 0 \\ 0 & \ddots & 0 \\ 0 & \vdots & \vdots & 0 \\ 0 & \dots & 0 & e^{-\alpha d/|\cos \theta_m|} \end{bmatrix}$$

- Now, we have turned the complex optics problem into matrix multiplication
- In the code:



whole\_stack = Structure([front\_surf, bulk\_mat, back\_surf], incidence=Air, transmission=Air)

#### Further reading: https://rayflare.readthedocs.io/en/latest/Theory/theory.html



## 8. Textured Si: pyramids/grating



Figures from: https://doi.org/10.1364/OE.23.0A1720



#### 9a. III-V on Si, planar vs. rear grating, using ARMM



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https://doi.org/10.1038/s41560-018-0125-0

## 9b. III-V on Si, planar vs. pyramidal Si texture

Use same III-V layer stack as previous example, but assume Si is pyramidally textured on both sides, and epoxy/glass is used to mechanically connect the III-V layers to the Si.

Use rt\_structure to define stack



**Extremely not to scale!** Epoxy/glass is orders of magnitude thicker than GaAs/GaInP!



#### 10. Conformal perovskite on pyramidal Si texture







#### Figures from: <u>https://doi.org/10.1038/s41563-018-0115-4</u>

# Thank you!

We would really appreciate your feedback: <a href="https://tinyurl.com/bdu29k3x">https://tinyurl.com/bdu29k3x</a>

